

# C1825C390JDGACTU

Aliases (C1825C390JDGAC7800) SMD Comm COG HV, Ceramic, 39 pF, 5%, 1,000 VDC, COG, SMD, MLCC, Ultra-Stable, Low Loss, Class I, 1825, 2.3 mm



Click here for the 3D model.

General Information		
Series	SMD Comm COG HV	
Style	SMD Chip	
Description	SMD, MLCC, Ultra-Stable, Low Loss, Class I	
Features	Ultra-Stable, Low Loss, Class I	
RoHS	Yes	
Termination	Tin	
Marking	No	
AEC-Q200	No	
Typical Component Weight	230 mg	
Shelf Life	78 Weeks	
MSL	1	

0% Loss/Decade Hour

100 GOhms

	Specifications	
	Capacitance	39 pF
+/-0.3mm	Measurement Condition	1 MHz 1.0Vrms
+/-0.4mm	Tolerance	5%
/-0.20mm	Voltage DC	1000 VDC
MIN	Dielectric Withstanding Voltage	1,200 VDC
+/-0.35mm	Temperature Range	-55/+125°C
	Temp. Coefficient	COG
Omm, Plastic Tape	Capacitance Change with Reference to +25°C and 0 VDC Applied (TCC)	30 ppm/C, 1MegaHz 1.0Vrms
	Dissipation Factor	0.1% 1 MHz 1.0Vrms

Aging Rate

Insulation Resistance

Dimensions 1825 Chip Size 4.5mm + L W 6.4mm + Т 1.6mm +/ S 2.3mm M 0.6mm + В

### **Packaging Specifications**

Packaging Packaging Quantity

T&R, 180 1000

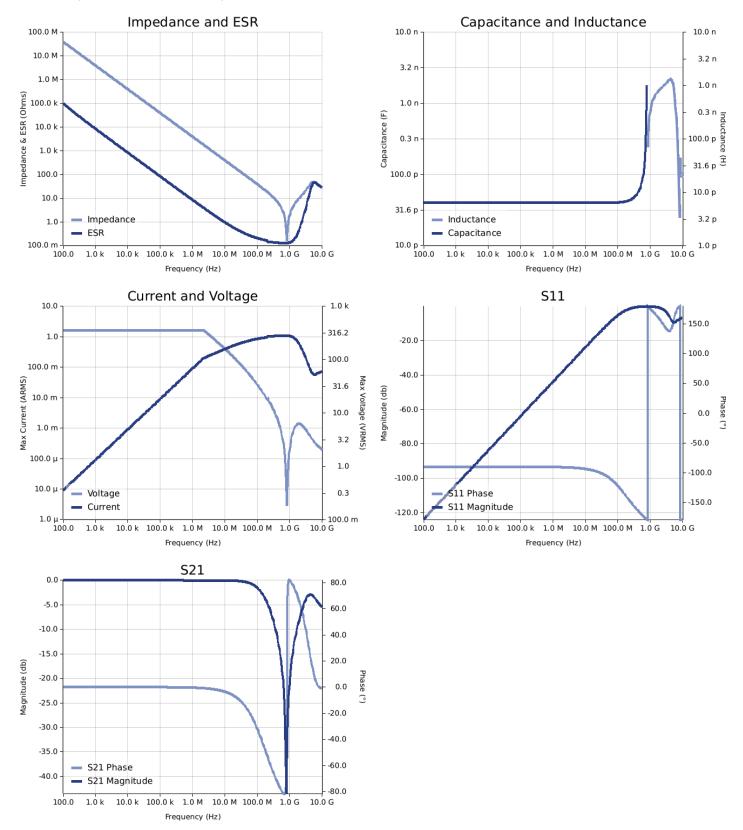
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C1825C390JDGACTU Aliases (C1825C390JDGAC7800) SMD Comm C0G HV, Ceramic, 39 pF, 5%, 1,000 VDC, C0G, SMD, MLCC, Ultra-Stable, Low Loss, Class I, 1825, 2.3 mm

### Simulations

For the complete simulation environment please visit K-SIM.





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#### These are simulations.

This is not a specification!

The responses shown represent the typical response for each part type. Specific responses may vary, depending on manufacturing variation affects of all parameters involved, including the specified tolerances applied to capacitance and unspecified variations of ESR, ESL, and leakage resistance.

The responses shown do not represent a specified or implied maximum capability of the device for all applications.

- The ESR used for ripple "Ripple Current/Voltage vs. Frequency" plots is the ESR at ambient temperature.

- The ESR used for https:// temperature Rise vs. Ripple Current/ voltage vs. Frequency plots is the ESR at ambient temperature.
  The ESR in the "Temperature Rise vs. Ripple Current" plots is adjusted to each incremental temperature rise before the power and ripple current is calculated.
  The effects shown herein are based on measured data from a multiple part sample of the parts in question.
  Ripple capability of this device will be factored by thermal resistance (Rth) created by circuit traces (addi affects of all parameters involved, including the specified tolerances applied to capacitance and unspecified variations of ESR, ESL, and leakage resistance.
  The peak voltages generated in the "Temperature Rise vs. Combined Ripple Currents" plot are calculated for each frequency and are not combined with voltages
- generated at any other harmonics. Please consult with the catalog or field applications engineer for maximum capability of the device in specific applications.

All product information and data (collectively, the "Information") are subject to change without notice.

KEMET K-SIM is designed to simulate behavior of components with respect to frequency, ambient temperature, and DC bias levels. The responses shown represent the typical response for each part type. Specific responses may vary, depending on manufacturing variation effects of all parameters involved, including the specified tolerances applied to capacitance and unspecified variations of ESR, ESL, and leakage resistance.

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If you have any questions please contact K-SIM.